

International IOR Rectifier

11DQ05
11DQ06

SCHOTTKY RECTIFIER

1.1 Amp

Major Ratings and Characteristics

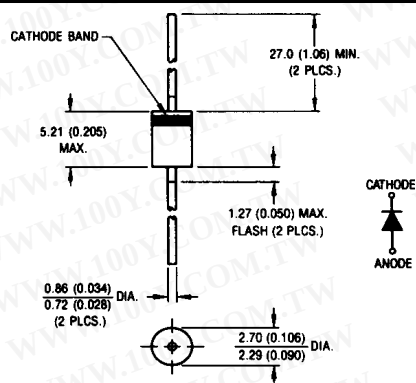
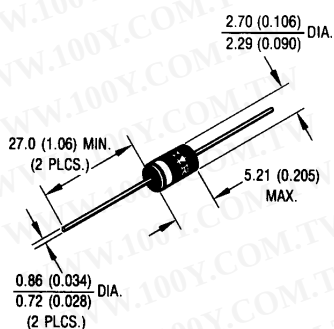
Characteristics	11DQ..	Units
$I_{F(AV)}$ Rectangular waveform	1.1	A
V_{RRM}	50/60	V
I_{FSM} @ $t_p=5\mu s$ sine	150	A
V_F @ 1 Apk, $T_J=125^\circ C$	0.53	V
T_J range	-40 to 150	$^\circ C$

Description/ Features

The 11DQ.. axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability

CASE STYLE AND DIMENSIONS



Conform to JEDEC Outline DO-204AL (DO-41)
Dimensions in millimeters and inches

11DQ05, 11DQ06

Bulletin PD-2.288 rev. E 03/03

International
IR Rectifier

Voltage Ratings

Part number	11DQ05	11DQ06
V_R Max. DC Reverse Voltage (V)	50	60
V_{RWM} Max. Working Peak Reverse Voltage (V)		

Absolute Maximum Ratings

Parameters	11DQ..	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current * See Fig. 4	1.1	A	50% duty cycle @ $T_C = 84^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current * See Fig. 6	150	A	5 μs Sine or 3 μs Rect. pulse
	25		10ms Sine or 6ms Rect. pulse
E_{AS} Non-Repetitive Avalanche Energy	2.0	mJ	$T_J = 25^\circ\text{C}$, $I_{AS} = 1$ Amps, $L = 4$ mH
I_{AR} Repetitive Avalanche Current	1.0	A	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. $V_A = 1.5 \times V_R$ typical

Electrical Specifications

Parameters	11DQ..	Units	Conditions
V_{FM} Max. Forward Voltage Drop * See Fig. 1 (1)	0.58	V	@ 1A
	0.76	V	@ 2A
	0.53	V	@ 1A
	0.64	V	@ 2A
I_{RM} Max. Reverse Leakage Current * See Fig. 2 (1)	1.0	mA	$T_J = 25^\circ\text{C}$
	11	mA	$T_J = 125^\circ\text{C}$
C_T Typical Junction Capacitance	55	pF	$V_R = 5V_{DC}$ (test signal range 100Khz to 1Mhz) 25°C
L_S Typical Series Inductance	8.0	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	10000	V/ μs	(Rated V_R)

(1) Pulse Width < 300 μs , Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	11DQ..	Units	Conditions
T_J Max. Junction Temperature Range (*)	-40 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-40 to 150	$^\circ\text{C}$	
R_{thJA} Max. Thermal Resistance Junction to Ambient	100	$^\circ\text{C/W}$	DC operation Without cooling fin
R_{thJL} Typical Thermal Resistance Junction to Lead	81	$^\circ\text{C/W}$	DC operation (See Fig. 4)
wt Approximate Weight	0.33(0.012)	g (oz.)	
Case Style	DO-204AL(DO-41)		

(*) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

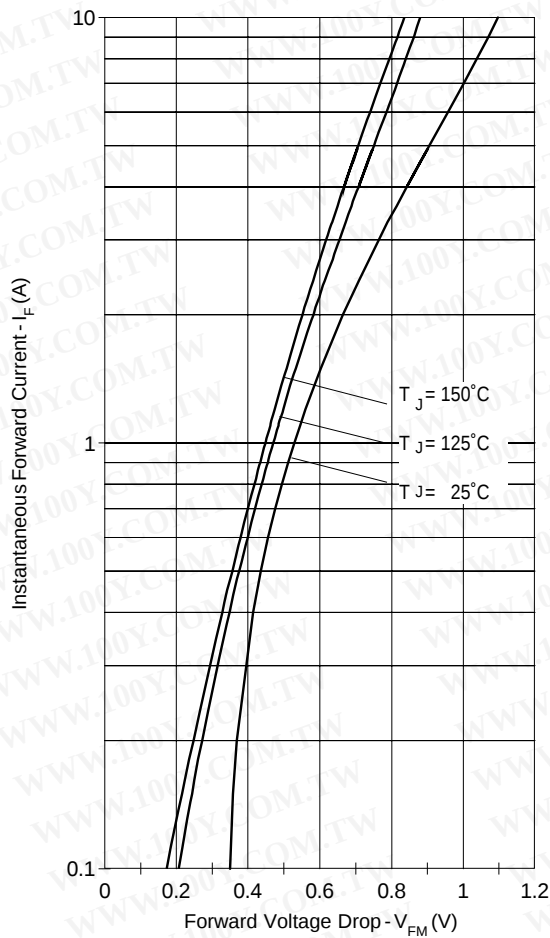


Fig. 1 - Maximum Forward Voltage Drop Characteristics

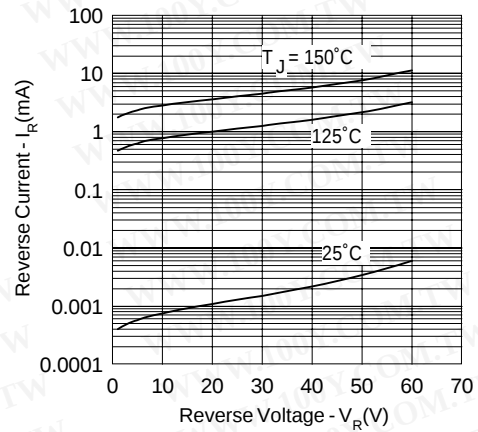


Fig. 2 - Typical Values of Reverse Current Vs. Reverse Voltage

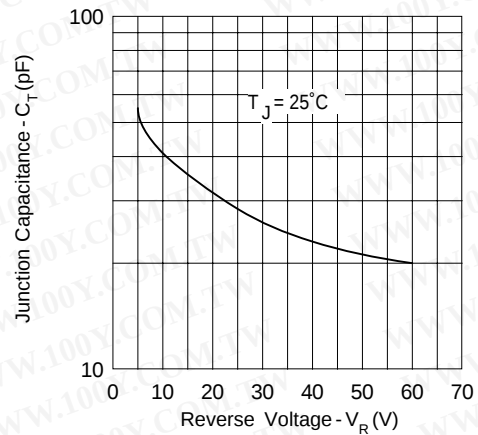


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

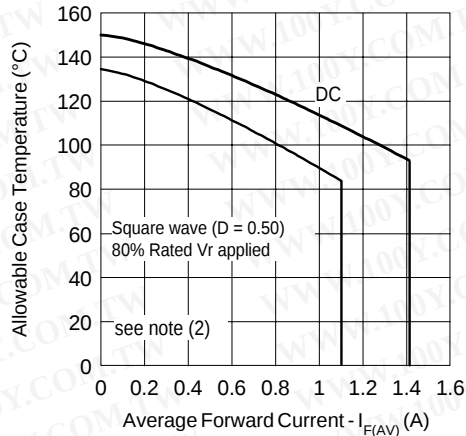


Fig. 4 - Maximum Ambient Temperature Vs. Average Forward Current, Printed Circuit Board Mounted

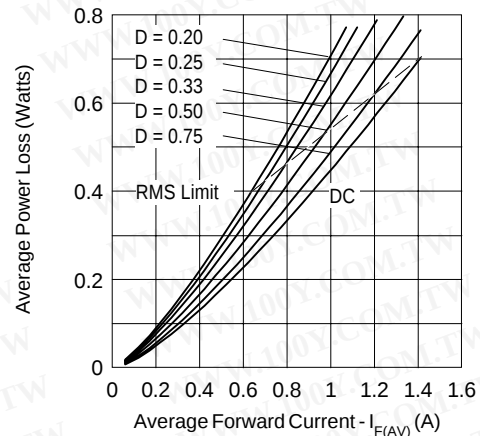


Fig. 5 - Forward Power Loss Characteristics

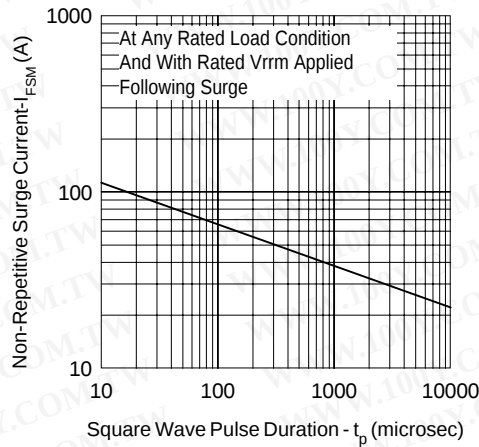


Fig. 6 - Maximum Non-Repetitive Surge Current

(2) Formula used: $T_c = T_j - (P_d + P_{d_{REV}}) \times R_{thJC}$;

P_d = Forward Power Loss = $I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);

$P_{d_{REV}}$ = Inverse Power Loss = $V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = 80\%$ rated V_R

Ordering Information Table

Device Code				
11	D	Q	06	TR
①	②	③	④	⑤
1	- 11 = 1.1A (Axial and small packages - Current is x10)			
2	- D = DO-41 package			
3	- Q = Schottky Q.. Series			
4	- 10 = Voltage Ratings			
5	- TR = Tape & Reel package (5000 pcs) - = Box package (1000 pcs)			

06 = 60V
05 = 50V

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IR Rectifier

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